



# ESD PADS

for DEEP Submicron design  
rules using TSMC CL018 process

$$\lambda = 90 \text{ nm}$$

Technology code:

SCN6M\_DEEP

Electric Technology: mocmos  
(submicron)



# List of Pads

- Digital Input/Output pad
- Analog pad
- VDD pad
- GND pad

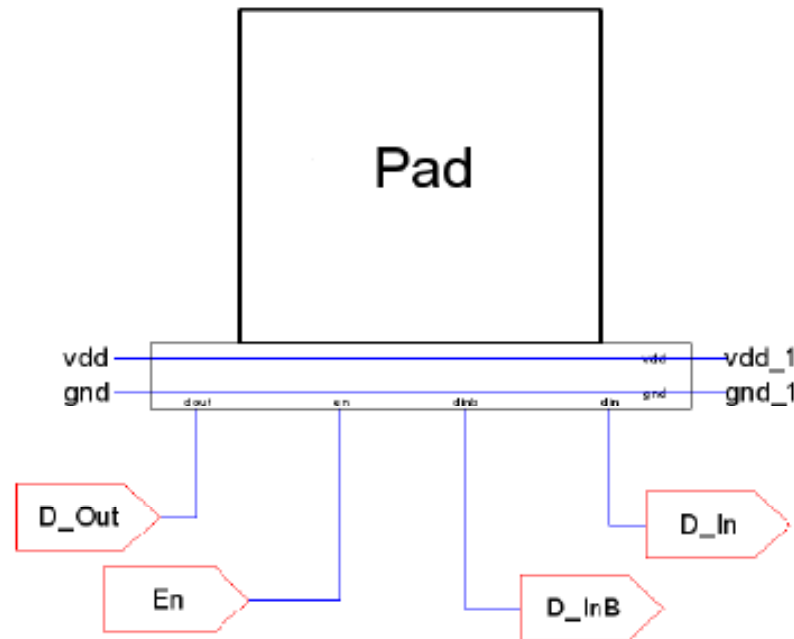


All digital pads contain following pins:

- Inputs: `En`, `D_Out`
- Outputs: `D_In`, `D_InB`
- Bidirectional pin: `pad`
- Power: `vdd`
- Ground: `gnd`



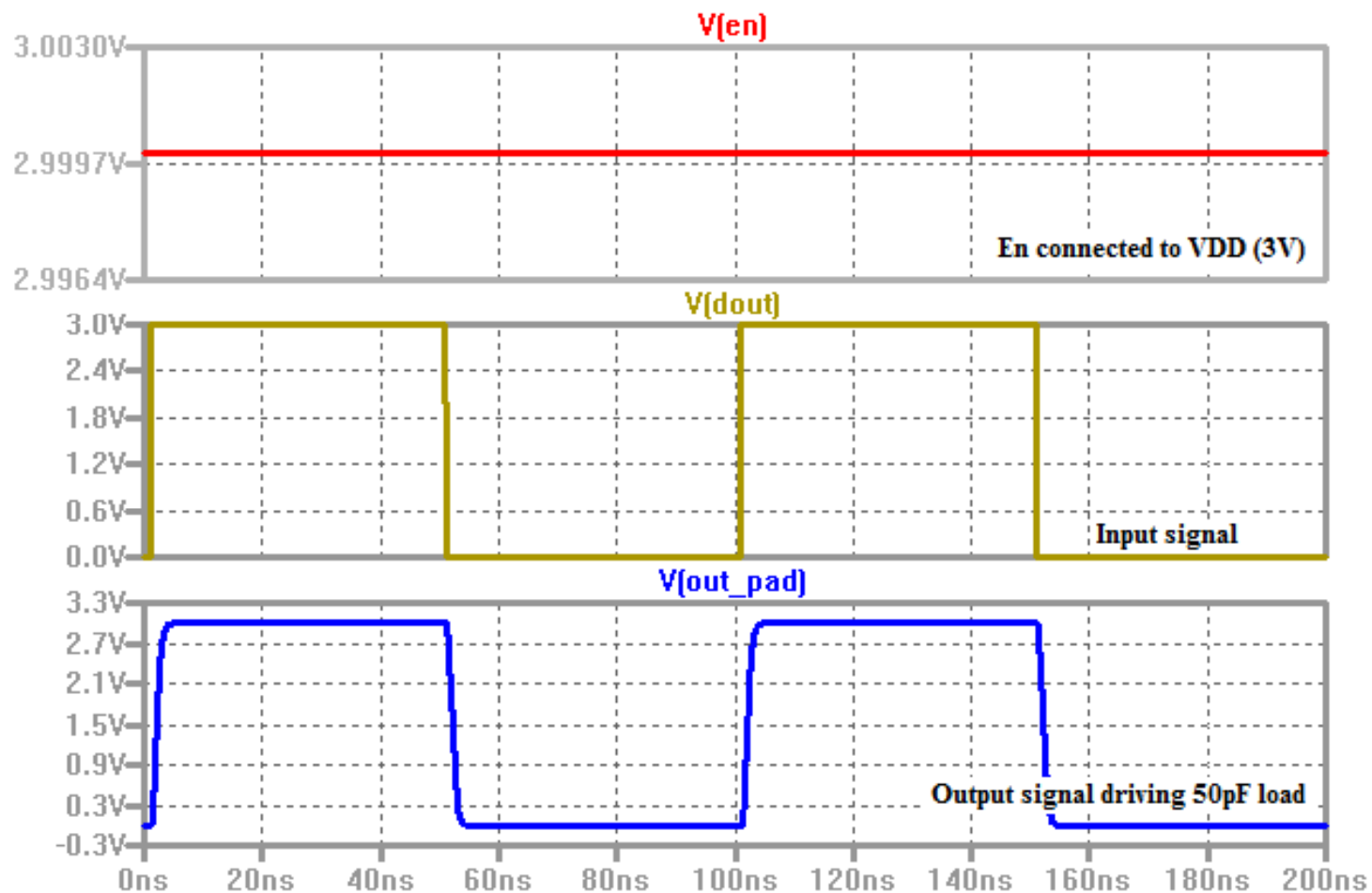
Using Digital Input/Output pad for signals coming on to the chip



- Connect En to VDD.
- Connect D\_Out to the input signal.
- Pad is the output.

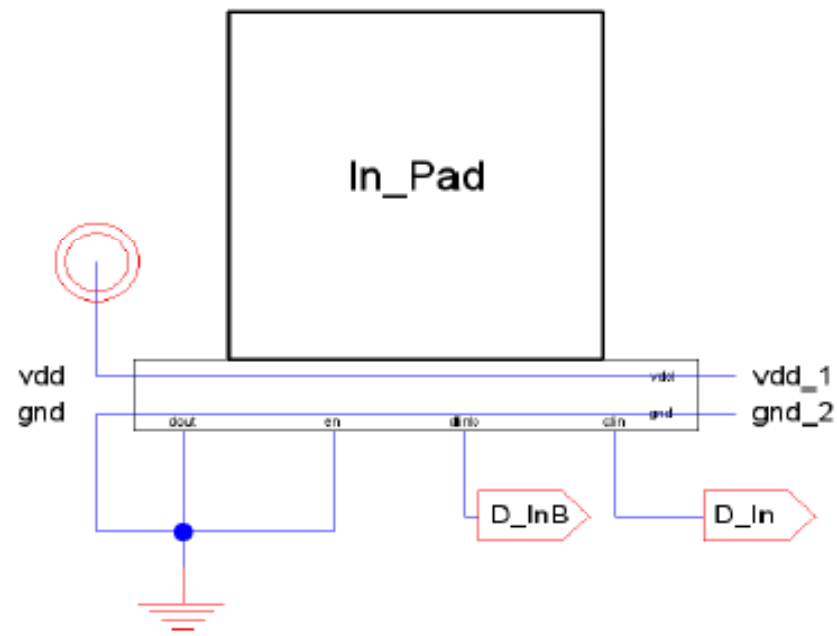


Simulation of Input/Output pad used for signals coming on to the chip





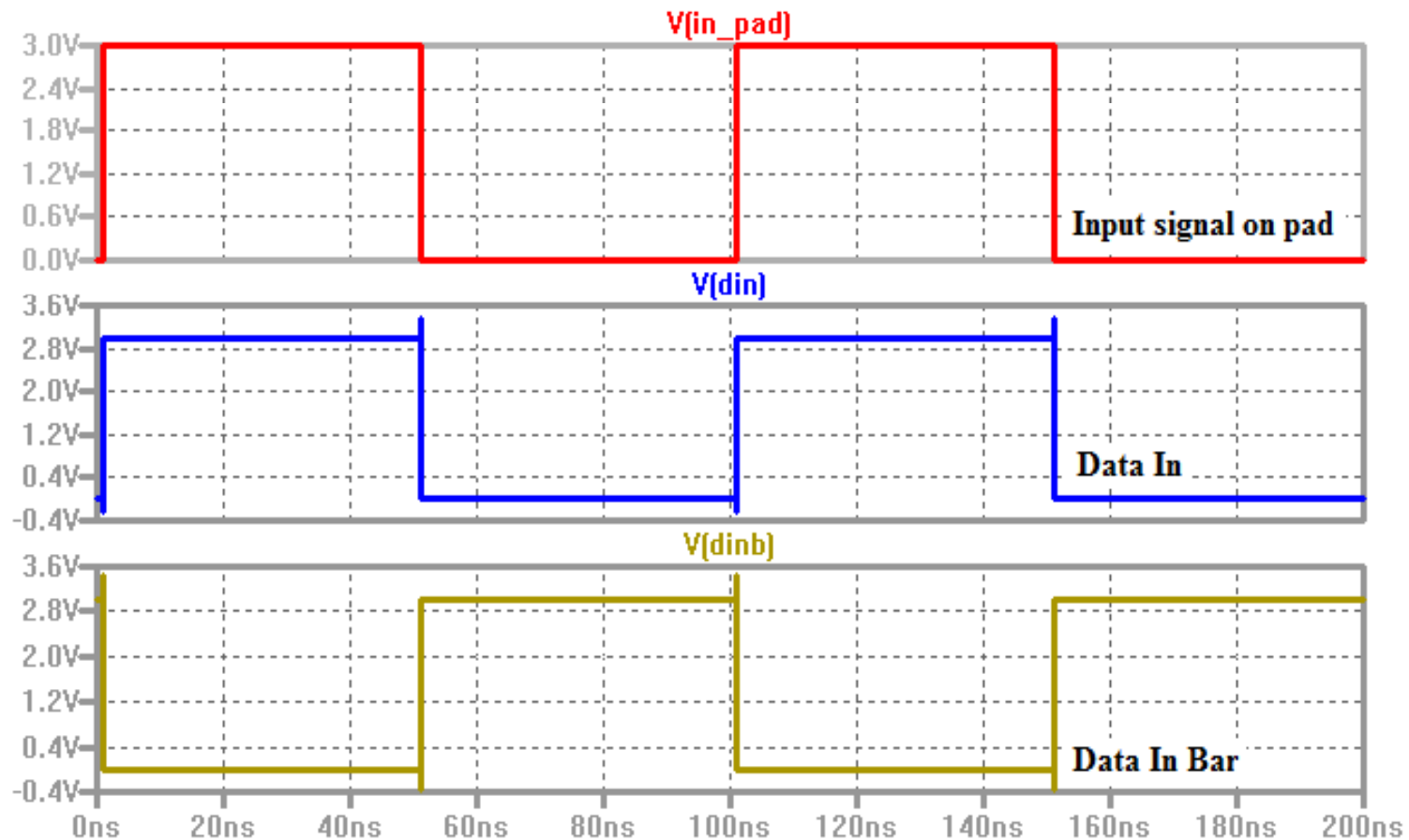
## Using Digital Input/Output pad for **driving signals off-chip**



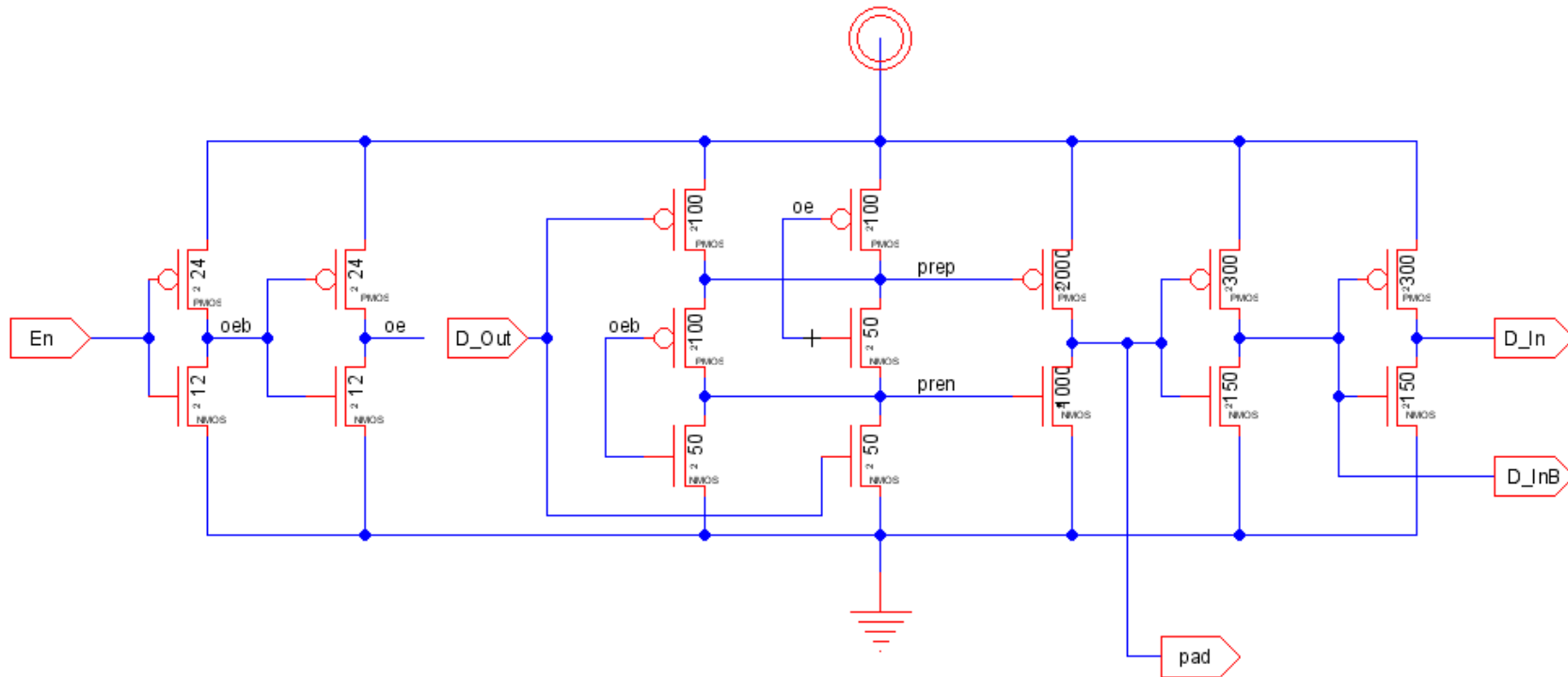
- En is connected to gnd.
- D\_Out is a don't care, here it is connected to ground but it could be floating (unconnected).
- The input signal is connected to the pad and the output will be available at D\_In. D\_InB is the inverted signal of D\_In.



## Simulation of Input/Output pad for providing signals off-chip



# Digital Input/Output Pad Schematic



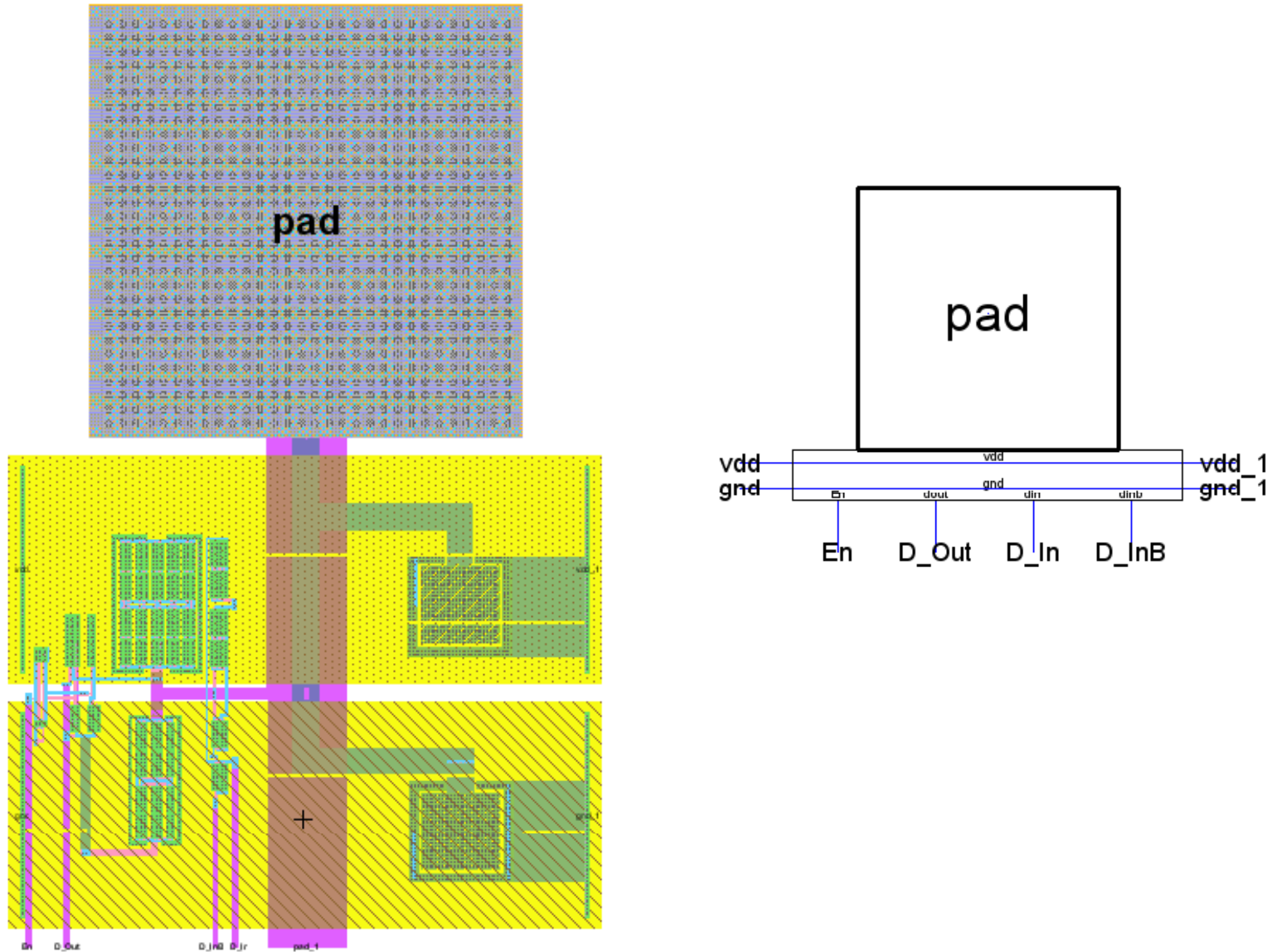
As explained in the previous slides,

- En and D\_Out are the input signals, while pad, D\_In, and D\_InB are output signals.
- Using the pad as an input requires En to be grounded and D\_out as don't care. The input signal is provided on pad and the output will be available at D\_In.
- Using the pad as an output requires En to be connected to the power (vdd) and D\_Out should be connected to the input signal while the output appears on the pad.



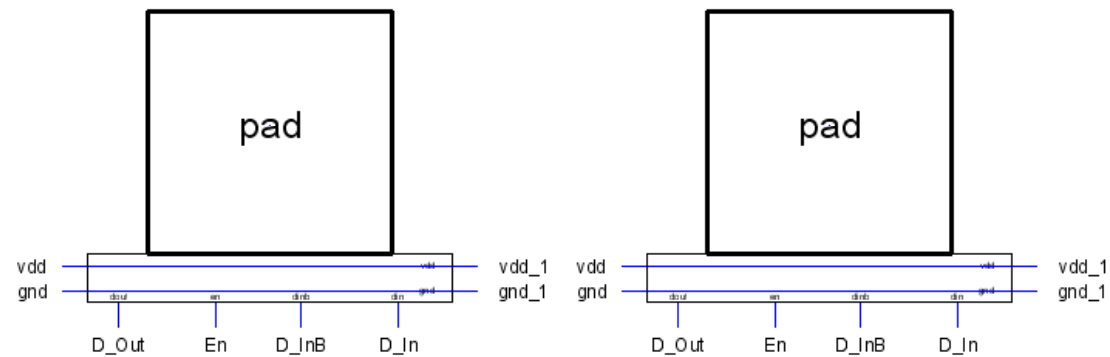


## Layout and Icon view of Input/Output pad

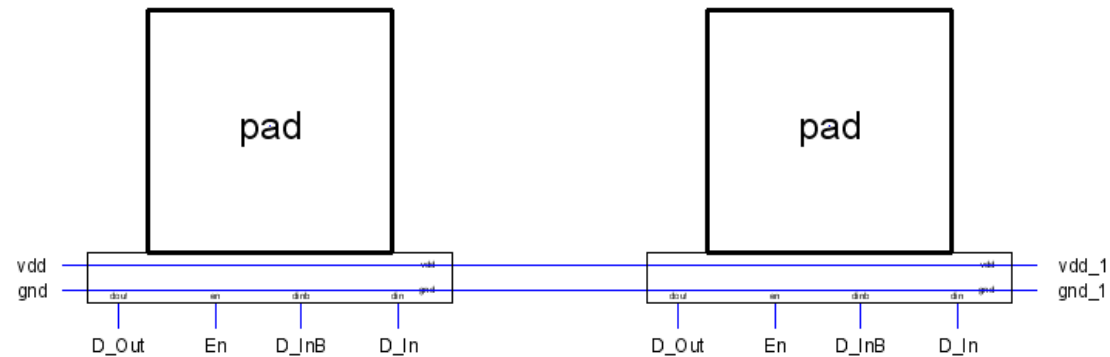




## Connecting two pads together



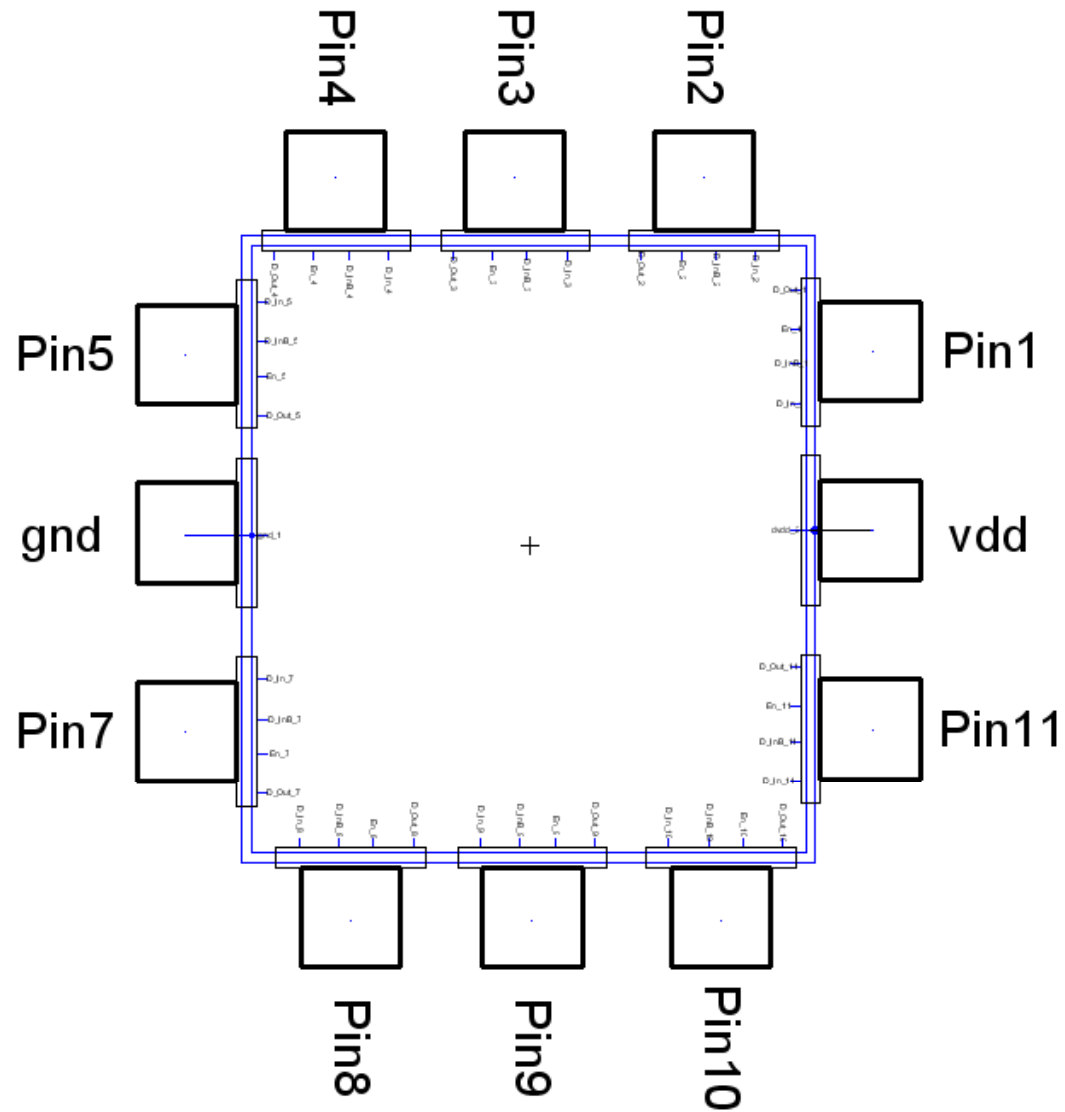
A) Take the icon of the Input/Output pad and copy it.



B) Connect the vdd and gnd connections of two pads.

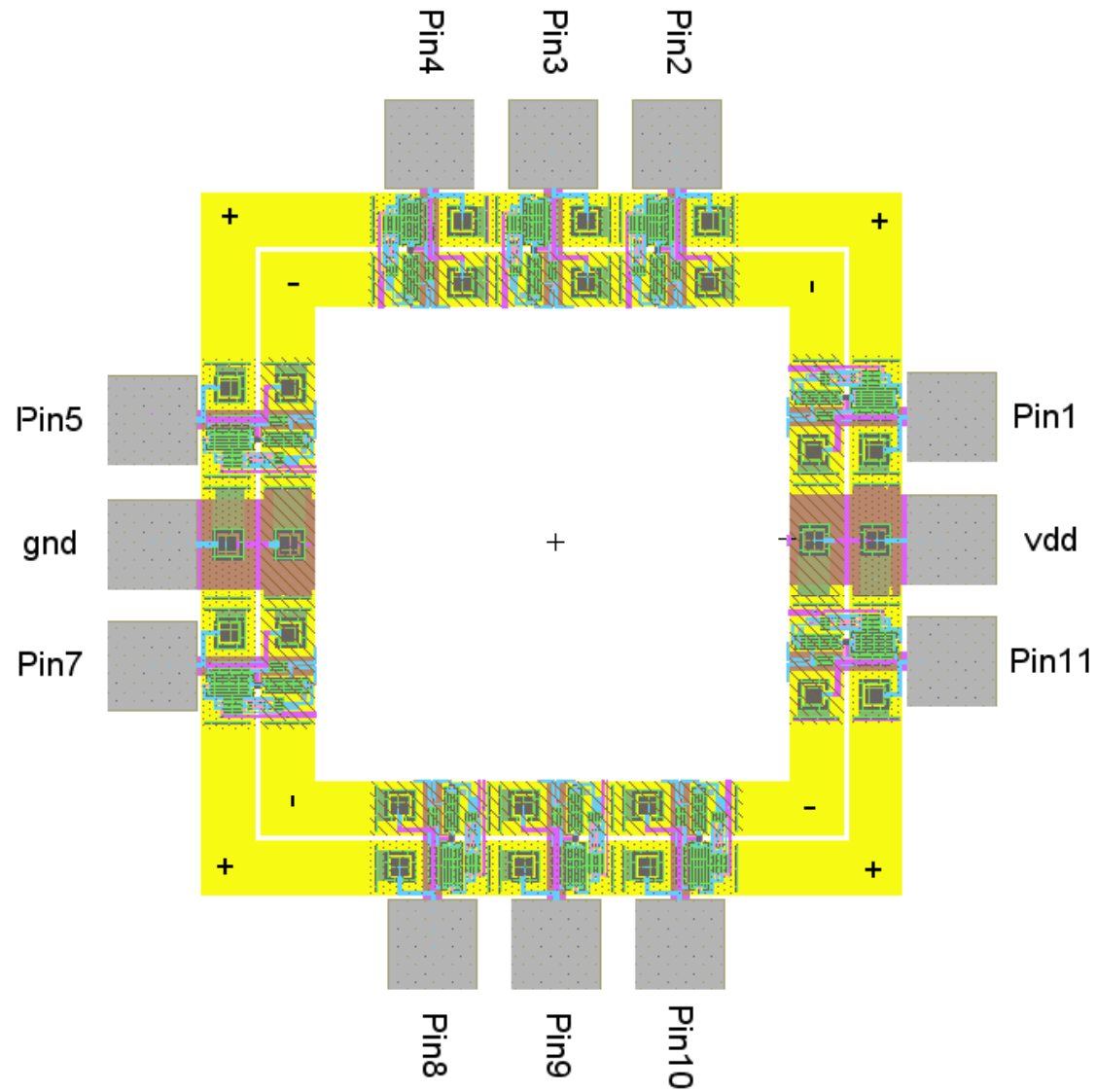


## 12 Pin pad frame using Input/output pads

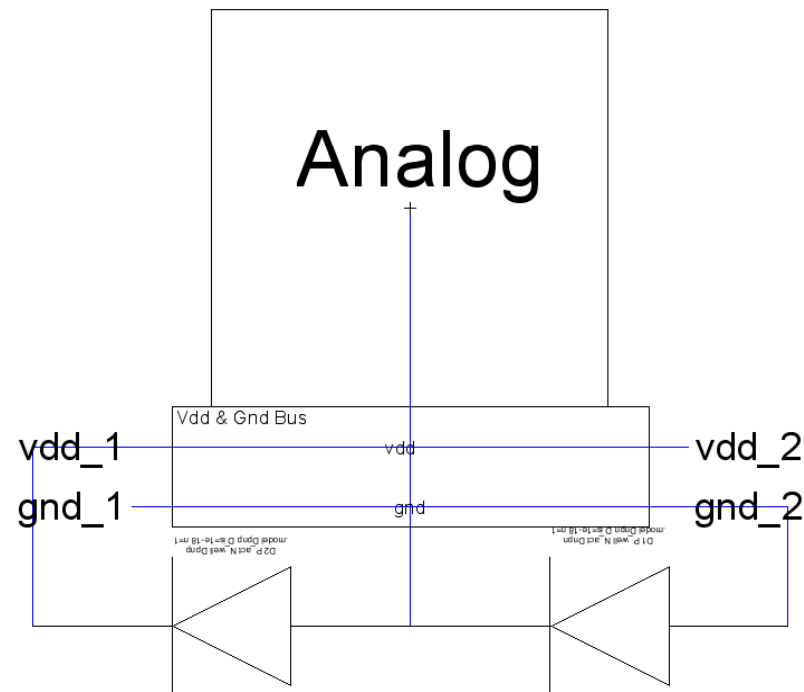




## 12 Pin pad frame Layout using input/output pads



# Analog Pad

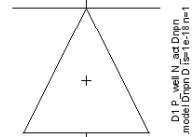


The pad contains diodes for ESD (Electrostatic Discharge) Protection. When the pad gets voltage higher than VDD, the P\_act to Nwell diode turns on and supplies the extra voltage to vdd source. Similarly if the pad gets voltage lower than ground (negative voltage), the N\_act to Pwell diode turns on supplying the negative voltage to the ground. Both the diodes protect the pad from damages.



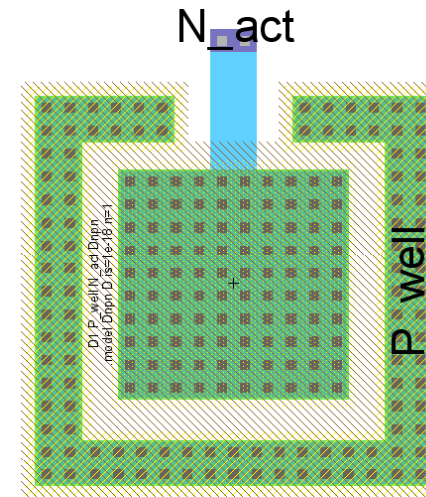
## ESD diodes and Layout

N\_act



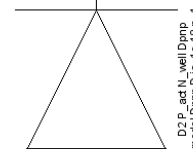
D1 P\_well N\_act Dpn  
model Dpn D [se=1e-18 n=1]

P\_well



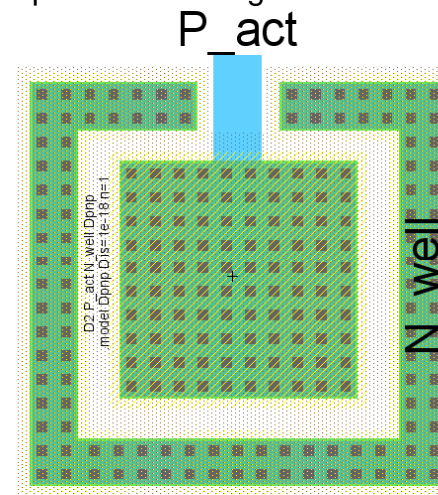
N\_act is connected to pad and p\_well is connected to ground. If the voltage on pad goes below ground (0 volt) the diode turns on and drives the negative voltage to ground preventing the pad from damage.

N\_well



D2 P\_act N\_well Dnp  
model Dnp D [se=1e-18 n=1]

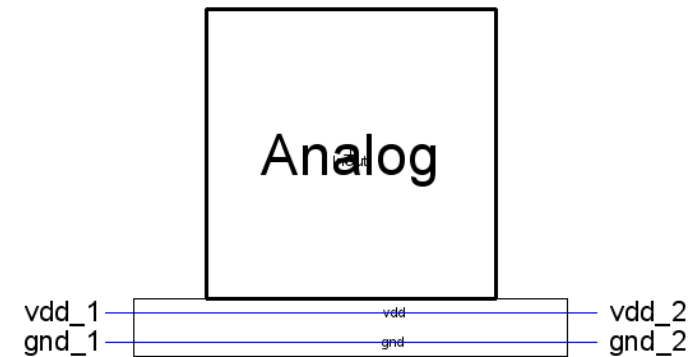
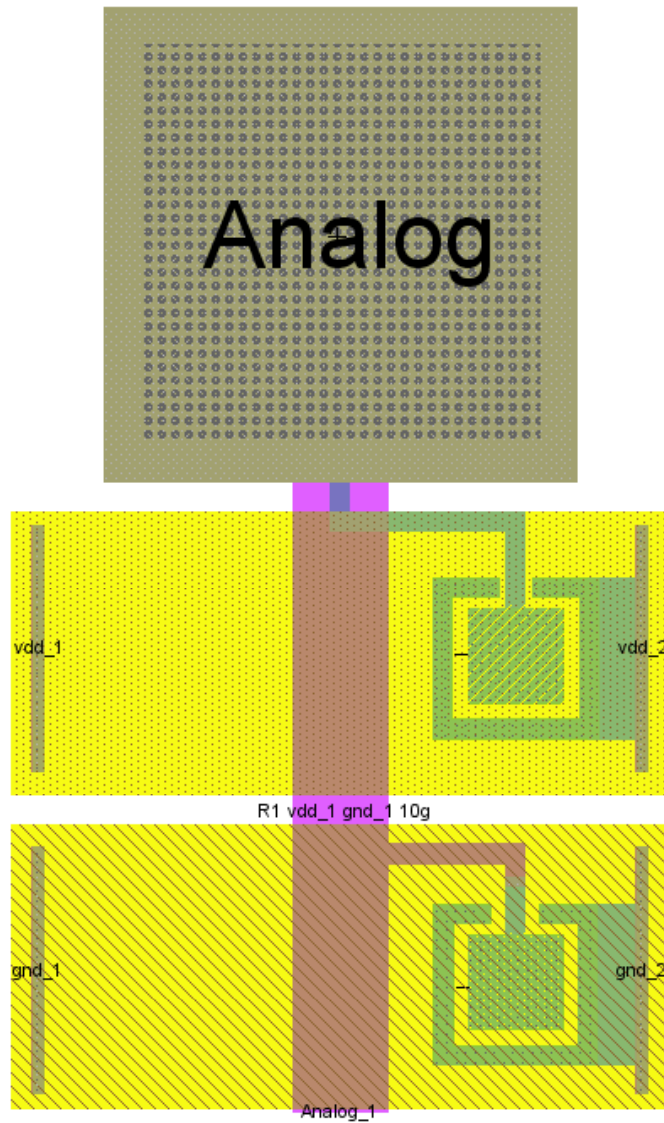
P\_act



P\_act is connected to pad and n\_well is connected to power. If the voltage on pad goes above vdd (5 volt) the diode turns on and drives the extra voltage to power preventing the pad from damage.



## Layout and Icon view of analog pad





## 12 Pin pad frame using analog pads

